

View Online at <https://aerobasegroup.com/nsn/5961-01-378-6022>

Inclosure Material:

Metal all semiconductor device diode

Overall Length:

0.325 inches all semiconductor device diode and 0.335 inches all semiconductor device diode

Overall Height:

0.135 inches all semiconductor device diode

Overall Width:

0.245 inches all semiconductor device diode and 0.251 inches all semiconductor device diode

Function For Which Designed:

Tunnel diode

Component Name And Quantity:

2 semiconductor device diode

Field Force Effect Type:

Electrostatic charge

Semiconductor Material:

Silicon all semiconductor device diode

Power Rating Per Characteristic:

50.0 milliwatts small-signal output power, common-base minor all semiconductor device diode

Maximum Operating Temperature Per Measurement Point:

100.0 degrees celsius junction all semiconductor device diode

Test Data Document:

30003-704as11964 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Terminal Type And Quantity:

2 pin all semiconductor device diode

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

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